Analog Electronic Circuits (EC2.103): Quiz-1

Instructor: Prof. Abhishek Srivastava, CVEST, IIIT Hyderabad Date: 30th Jan, 2024, Duration: 1 hour, Max. Marks: 10

Instructions:

- · Clearly write your valid assumptions (if any)
- You can use one A4 sheet own handwritten short notes in the exam hall
- · Mobile phone, computers can not be used during exam
- 1. (a) Find $V_{C2}(t)$ as a function of time for the circuit given below in Fig. 1. Assume that C_2 was completely discharged at $t = 0^-$. [1 Mark]

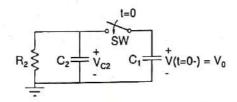


Figure 1

(b) I-V characteristic of a diode is shown in Fig. 2. Find dynamic resistance of the diode at points A and B as shown in the graph. [I Mark]

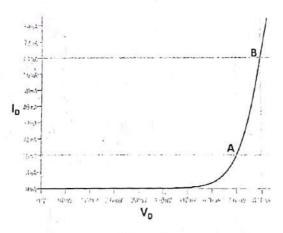


Figure 2

- (c) Draw Bode magnitude and phase plots for the transfer function $H(s) = \frac{1}{(s+10)(s+50)}$. [1 Mark]
- (d) For a uniformly doped n-type semiconductor bar having length of 2 μm and cross sectional area of 0.25 μm^2 , find the drift current density (*J*) and total current (*I*) flowing through it, when a voltage of 1 *V* is applied across the bar. It is given that $N_D = 10^{16}/cm^3$, $n_i = 1.5 \times 10^{10}/cm^3$, $e = 1.6 \times 10^{-19}$ *C* and $\mu_n = 1350$ cm^2/VS . [2 Mark]
- 2. For the circuit shown in figure 3, find V_{out} for the two cases given below. Validate your assumptions (if any).

(a)
$$V_1 = 10 V$$
 and $V_2 = 0 V$

[1 Mark]

(b)
$$V_1 = 10 V$$
 and $V_2 = 10 V$

[1 Mark]

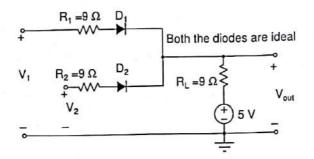


Figure 3

- 3. (a) For the circuit shown in figure 4(a), plot voltage transfer characteristic $(V_{OUT} \text{ vs } V_{IN})$ considering ideal diodes. Also plot $V_{OUT}(t)$ as a function of time for $V_{in} = 20cos(\omega_0 t) V$. Clearly label axis and values on all plots to get any credit. [1 Mark]
 - (b) For the circuit shown in figure 4(b), prove that both the diodes remain on for all values of input voltage. Considering diode cut-in voltage V_{ν} and on resistance R_{on} , derive V_{OUT} as a function of V_{IN} .

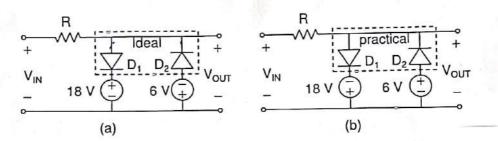


Figure 4

Good luck!!